

PHOTOTRANSISTOR

Part Number: WP7113P3C

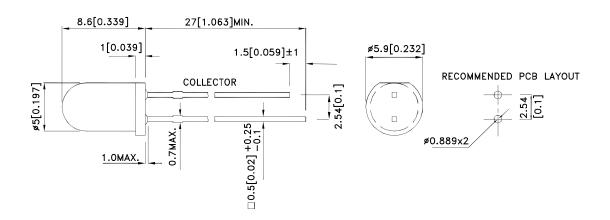
Features

- Mechanically and spectrally matched to the infrared emitting LED lamp .
- Water clear lens.
- RoHS compliant.

Description

Made with NPN silicon phototransistor chips.

Package Dimensions



- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- 3. Lead spacing is measured where the leads emerge from the package.
 4. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

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Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
VBR CEO	Collector-to-Emitter Breakdown Voltage	30			V	Ic=100uA Ee=0mW/c m²
VBR ECO	Emitter-to-Collector Breakdown Voltage	5			V	IE=100uA Ee=0mW/c m³
VCE (SAT)	Collector-to-Emitter Saturation Voltage			0.8	V	Ic=2mA Ee=20mW/c m²
I CEO	Collector Dark Current			100	nA	Vc=10V Ee=0mW/c m³
TR	Rise Time (10% to 90%)		15		us	VcE = 5V Ic=1mA RL=1000Ω
TF	Fall Time (90% to 10%)		15		us	
I (ON)	On State Collector Current	0.5	2.5		mA	VcE = 5V Ee=1mW/c m ² λ=940nm

Absolute Maximum Ratings at TA=25°C

Parameter	Max.Ratings			
Collector-to-Emitter Voltage	30V			
Emitter-to-Collector Voltage	5V			
Power Dissipation at (or below) 25°C Free Air Temperature	100mW			
Operating Temperature	-40°C To +85°C			
Storage Temperature	-40°C To +85°C			
Lead Soldering Temperature (>5mm for 5sec)	260°C			

Typical Electro-Optical Characteristics Curves

Fig.1 Collector Power Dissipation vs.
Ambient Temperature

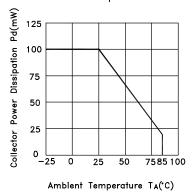
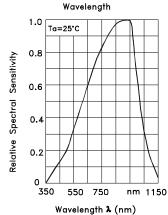


Fig.2 Spectral Sensitivity vs.



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Fig.3 Relative Collector Current vs. Ambient Temperature 160 Relative Collector Current(%) Vce=5V 140 Ee=1mW/cm 120 100 80 60 40 20 ō 10 20 30 40 50 60 Ambient Temperature Ta(°C)

Fig.5 Collector Dark Current vs.
AmbientTemperature

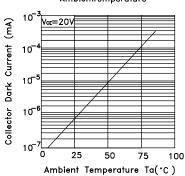


Fig.4 Collector Current vs.

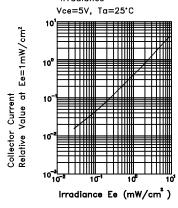


Fig.6 Collector Current vs.
Collector—Emitter Voltage

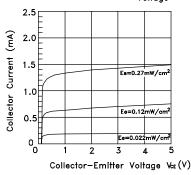
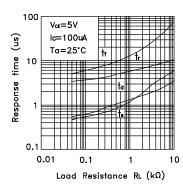
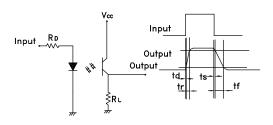


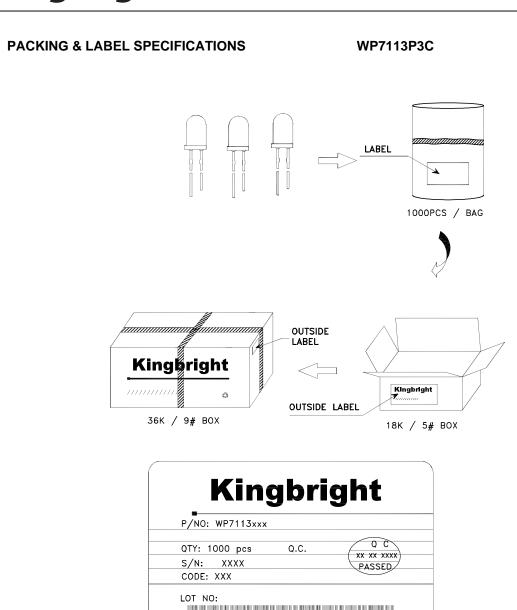
Fig.7 Response Time vs.Load Resistance



Test Circuit for Response Time



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1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.

RoHS Compliant

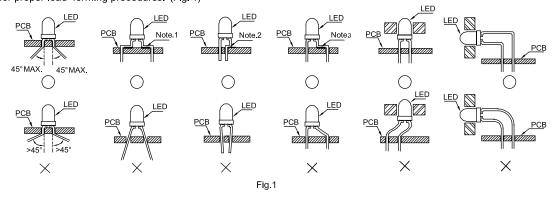
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PRECAUTIONS

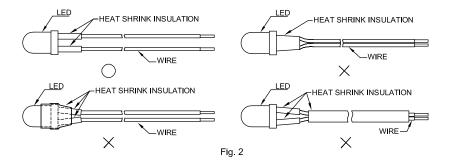
- 1. Storage conditions:
 - a. Avoid continued exposure to the condensing moisture environment and keep the product away from rapid transitions in ambient temperature.
 - b.LEDs should be stored with temperature ≦30°C and relative humidity < 60%.
 - c.Product in the original sealed package is recommended to be assembled within 72 hours of opening. Product in opened package for more than a week should be baked for 30 (\pm 10/-0) hours at 85 ~ 100°C.
- 2. The lead pitch of the LED must match the pitch of the mounting holes on the PCB during component placement. Lead-forming may be required to insure the lead pitch matches the hole pitch. Refer to the figure below for proper lead forming procedures. (Fig. 1)



"Correct mounting method "X" Incorrect mounting method

Note 1-3: Do not route PCB trace in the contact area between the leadframe and the PCB to prevent short-circuits.

3. When soldering wires to the LED, each wire joint should be separately insulated with heat-shrink tube to prevent short-circuit contact. Do not bundle both wires in one heat shrink tube to avoid pinching the LED leads. Pinching stress on the LED leads may damage the internal structures and cause failure. (Fig. 2)



4. Use stand-offs (Fig.3) or spacers (Fig.4) to securely position the LED above the PCB.

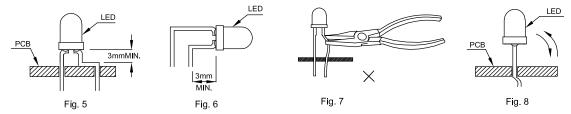


- 5. Maintain a minimum of 3mm clearance between the base of the LED lens and the first lead bend. (Fig. 5 and 6)
- 6. During lead forming, use tools or jigs to hold the leads securely so that the bending force will not be transmitted to the LED lens and its internal structures. Do not perform lead forming once the component has been mounted onto the PCB. (Fig. 7)

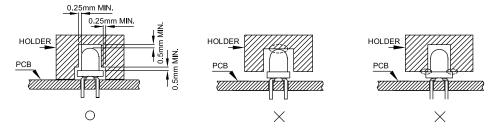
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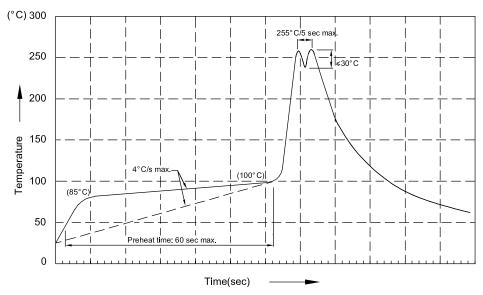
7. Do not bend the leads more than twice. (Fig. 8)



8. During soldering, component covers and holders should leave clearance to avoid placing damaging stress on the LED during soldering.



- 9. The tip of the soldering iron should never touch the lens epoxy.
- 10. Through-hole LEDs are incompatible with reflow soldering.
- 11. If the LED will undergo multiple soldering passes or face other processes where the part may be subjected to intense heat, please check with Kingbright for compatibility.
- 12. Recommended Wave Soldering Profiles:



Notes

- 1.Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
- 2.Peak wave soldering temperature between 245° C ~ 255° C for 3 sec (5 sec max).
- 3.Do not apply stress to the epoxy resin while the temperature is above 85°C.
- 4. Fixtures should not incur stress on the component when mounting and during soldering process.
- 5.SAC 305 solder alloy is recommended.
- 6.No more than one wave soldering pass.

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